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On January 27, 2003

TOWNSEND and TOWNSEND and CREW LLP

By: [Signature]

PATENT
Attorney Docket No.: 000939-045100US

Handwritten: H14/A
2/6/03

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Hsingya Arthur Wang, et al.

Application No.: 09/777,007

Filed: February 2, 2001

For: SOURCE SIDE PROGRAMMING

Examiner: Kiesha L. Rose

Art Unit: 2822

AMENDMENT

TECHNOLOGY CENTER 2800

FEB - 4 2003

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Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

In response to the Office Action mailed August 30, 2002, please amend the above-identified application as follows:

IN THE SPECIFICATION:

On page 1, please replace the sixth paragraph with the following paragraph:

-- FIG. 1 shows a cell 10 with a control gate 12, a floating gate 14, a source 16 and a drain 18. Control gate 12 and floating gate 14 are separated from source 16 and drain 18, and from a substrate 11 into which the source 16 and drain 18 are formed, by an oxide 22 which may be formed by one or more layers of a suitable oxide material. Suitable openings in the oxide 22 are provided to allow for external connection to source 16 and drain 18. As shown, connections are provided to set V_g (control gate voltage), V_d (drain voltage), V_s (source voltage) and V_b (substrate voltage). --